

# MOLDED THIN FILM CONTAINING SEMICONDUCTOR CRYSTAL PARTICLE, AND ITS USE

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## Abstract of JP2003138033

**PROBLEM TO BE SOLVED:** To provide a molded thin film excellent in transparency, surface hardness and antistatic properties, and having excellent characteristics, such as luminous characteristics, light absorption saturation characteristics and ultraviolet absorption characteristics, and a high refractive index. **SOLUTION:** The molded thin film contains semiconductor crystal particles having a polyalkylene glycol residue bonded to the surface through an amino group.

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